



## T1635H Series

### Snubberless™ high temperature 16 A Triacs

#### Main features

Symbol	Value	Unit
$I_{T(RMS)}$	16	A
$V_{DRM}/V_{RRM}$	600	V
$I_{GT(Q1)}$	35	mA

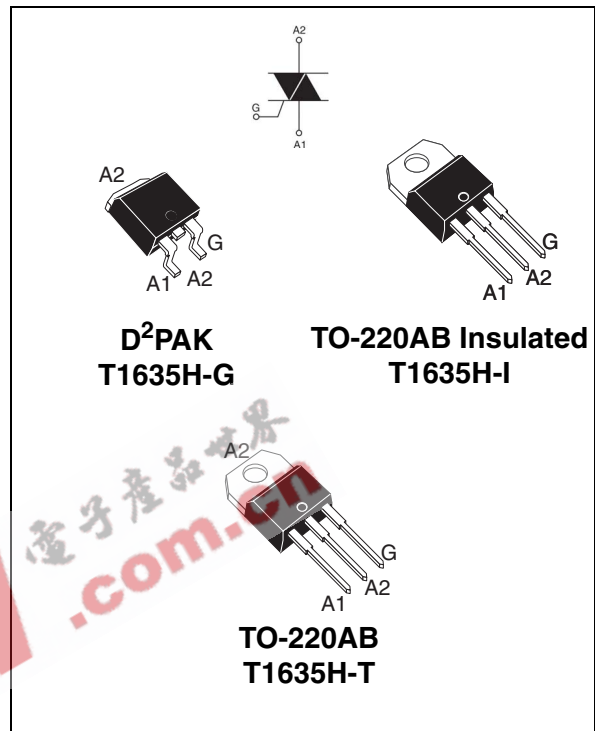
#### Description

Specifically designed to operate at 150° C, the new 16 A T1635H Triacs provide an enhanced performance in terms of power loss and thermal dissipation. This facilitates the optimization of heatsink dimensioning, leading to improved space and cost effectiveness when compared to electro-mechanical solutions.

Based on ST Snubberless™ technology, the T1635H series offers high commutation switching capabilities and high noise immunity levels on the full range of  $T_j$ .

The T1635H series facilitates the optimization of the control of universal motors and inductive loads found in appliances such as vacuum cleaners, and washing machines.

The T1635H Triacs are also suitable for use in high temperature environment found in hot appliances such as cookers, ovens, hobs, electric heaters, and coffee machines.



#### Order code

Part number	Marking
T1635H-600G	T1635H-600G
T1635H-600G-TR	T1635H-600G
T1635H-600TRG	T1635H-600T
T1635H-600IRG	T1635H-600I

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# 1 Characteristics

**Table 1. Absolute maximum ratings**

Symbol	Parameter		Value	Unit	
$I_{T(RMS)}$	RMS on-state current (full sine wave)	D <sup>2</sup> PAK TO-220AB	$T_c = 130^\circ\text{C}$	16	A
		TO-220AB Ins	$T_c = 110^\circ\text{C}$		
$I_{TSM}$	Non repetitive surge peak on-state current (full cycle sine wave, $T_j$ initial = $25^\circ\text{C}$ )	F = 60 Hz	t = 16.7 ms	170	A
		F = 50 Hz	t = 20 ms	160	
$I^2t$	$I^2t$ Value for fusing	tp = 10 ms		128	A <sup>2</sup> s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$ , tr ≤ 100 ns	F = 120 Hz	$T_j = 150^\circ\text{C}$	50	A/μs
$V_{DSM}/V_{RSM}$	Non repetitive surge peak off state voltage		$T_j = 25^\circ\text{C}$	700	V
$I_{GM}$	Peak gate current	t <sub>p</sub> = 20 μs	$T_j = 150^\circ\text{C}$	4	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 150^\circ\text{C}$	1	W
$T_{stg}$ $T_j$	Storage junction temperature range Operating junction temperature range			-40 to +150 -40 to +150	°C

**Table 2. Electrical characteristics ( $T_j = 25^\circ\text{C}$ , unless otherwise specified)**

Symbol	Test conditions	Quadrant		Value	Unit
$I_{GT}^{(1)}$	$V_D = 12\text{ V}$ , $R_L = 33\ \Omega$	II - III	MAX	35	mA
$V_{GT}$		II - III	MAX	1.3	V
$V_{GD}$	$V_D = V_{DRM}$ , $R_L = 3.3\ \text{k}\Omega$	II - III	MIN	0.15	V
$I_H^{(2)}$	$I_T = 100\ \text{mA}$		MAX	35	mA
$I_L$	$I_G = 1.2 \times I_{GT}$	I - III	MAX	50	mA
		II		80	
dV/dt <sup>(2)</sup>	$V_D = 67\% V_{DRM}$ , gate open, $T_j = 150^\circ\text{C}$		MIN	300	V/μs
(dI/dt) <sub>c</sub> <sup>(2)</sup>	Without snubber, $T_j = 150^\circ\text{C}$		MIN	7.1	A/ms

1. minimum  $I_{GT}$  is guaranteed at 5% of  $I_{GT}$  max
2. for both polarities of A2 referenced to A1

**Table 3. Static electrical characteristics**

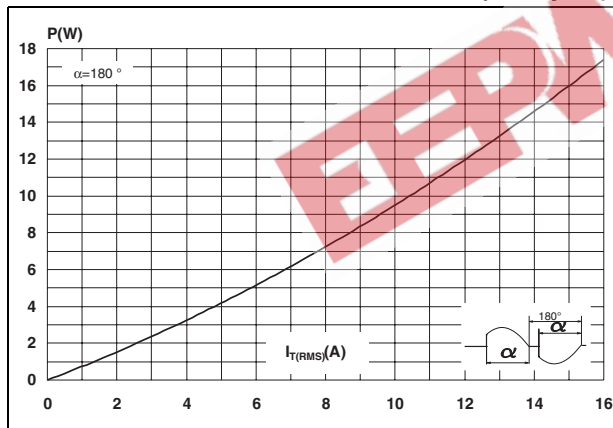
Symbol	Test conditions			Value	Unit
$V_{TM}^{(1)}$	$I_{TM} = 22.5\text{ A}$ , $t_p = 380\ \mu\text{s}$	$T_j = 25^\circ\text{ C}$	MAX	1.5	V
$V_{TO}^{(1)}$		$T_j = 150^\circ\text{ C}$	MAX	0.80	V
$R_D^{(1)}$		$T_j = 150^\circ\text{ C}$	MAX	23	m $\Omega$
$I_{DRM}$ $I_{RRM}$	$V_{DRM} = V_{RRM}$	$T_j = 25^\circ\text{ C}$	MAX	5	$\mu\text{A}$
		$T_j = 150^\circ\text{ C}$		6.4	mA
	$V_D/V_R = 400\text{ V}$ (at peak mains voltage)	$T_j = 150^\circ\text{ C}$		4.2	

1. for both polarities of A2 referenced to A1

**Table 4. Thermal resistance**

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	D <sup>2</sup> PAK TO-220AB	1.2	°C/W
		TO-220AB Ins	2.1	
$R_{th(j-a)}$	Junction to ambient	$S_{CU} = 1\text{ cm}^2$ D <sup>2</sup> PAK	45	
		TO-220AB TO-220AB Ins	60	

**Figure 1. Maximum power dissipation vs RMS on-state current (full cycle)**



**Figure 2. RMS on-state current vs case temperature (full cycle)**

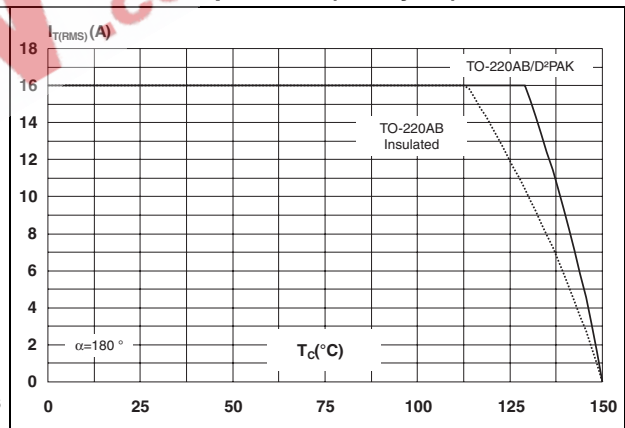


Figure 3. RMS on-state current vs ambient temperature, PCB FR4,  $e_{CU} = 35 \mu m$

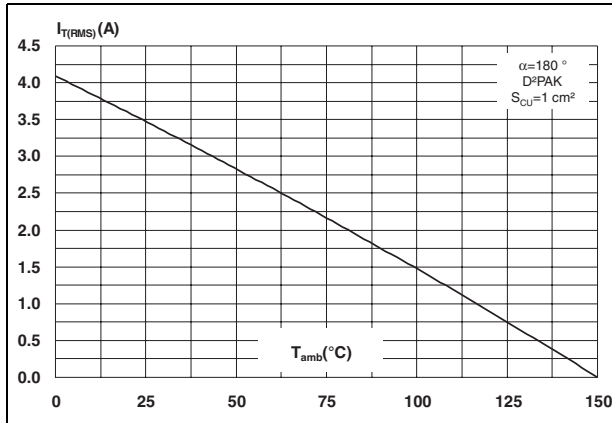


Figure 4. Relative variation of thermal impedance vs pulse duration

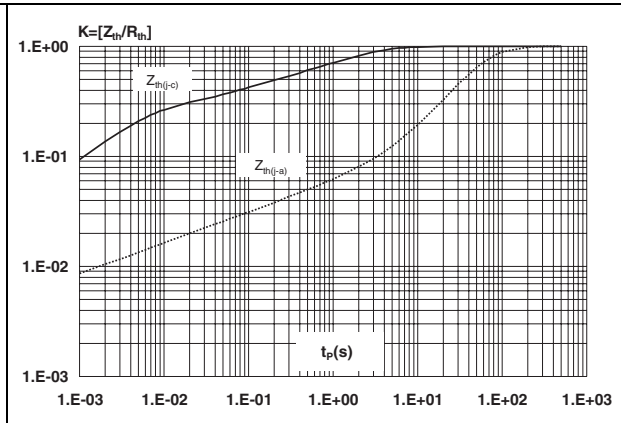


Figure 5. Relative variation of gate trigger current, holding current and latching current vs junction temperature (typical values)

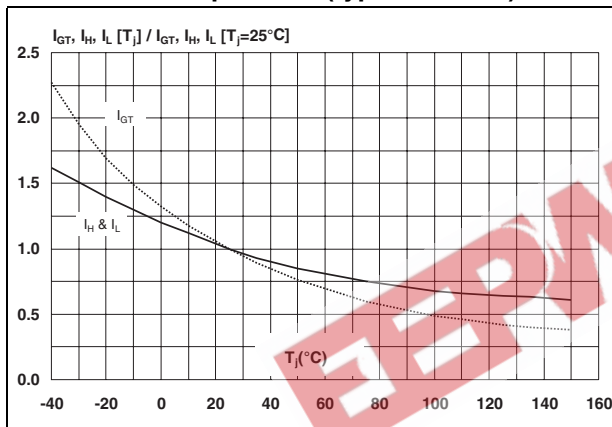


Figure 6. Surge peak on-state current vs number of cycles

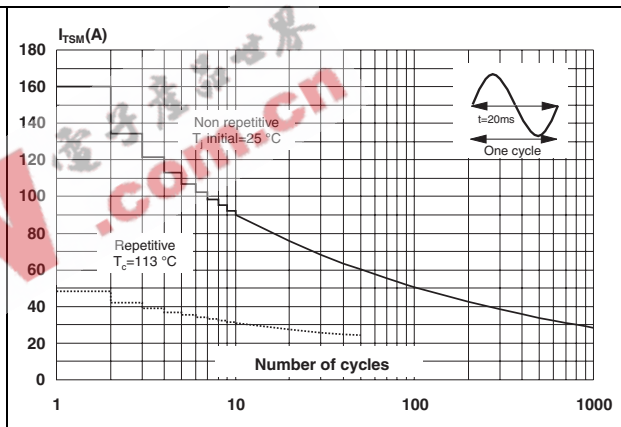


Figure 7. Non repetitive surge peak on-state current (sinusoidal pulse width  $t_p < 10 ms$ ) and corresponding value of  $I^2t$

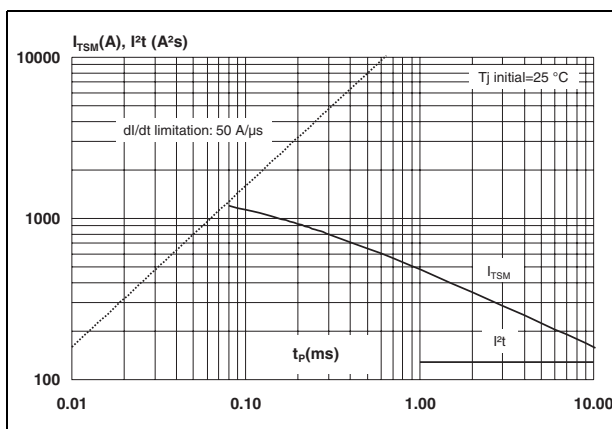
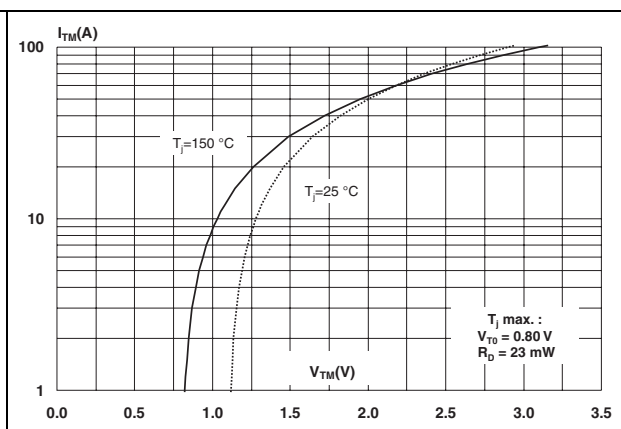
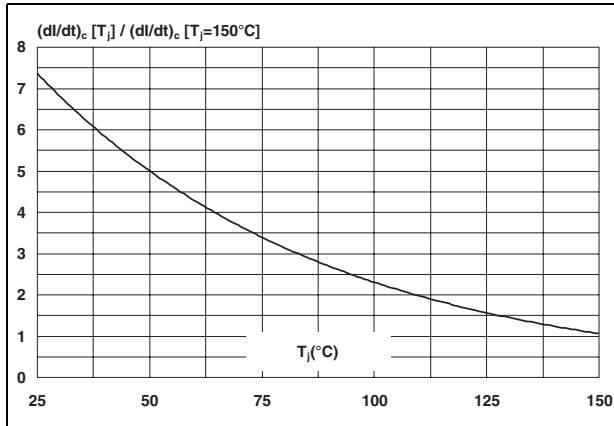


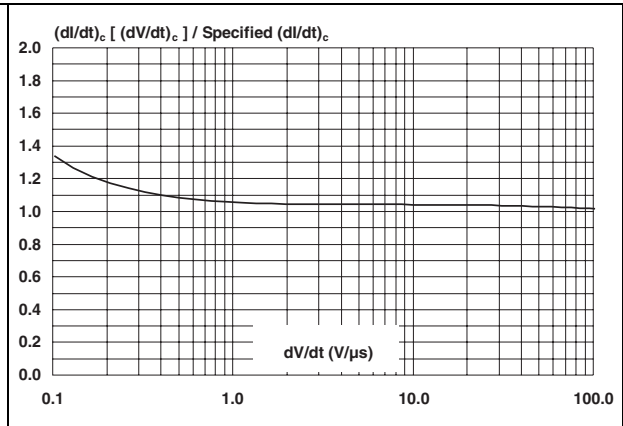
Figure 8. On-state characteristics (maximum values)



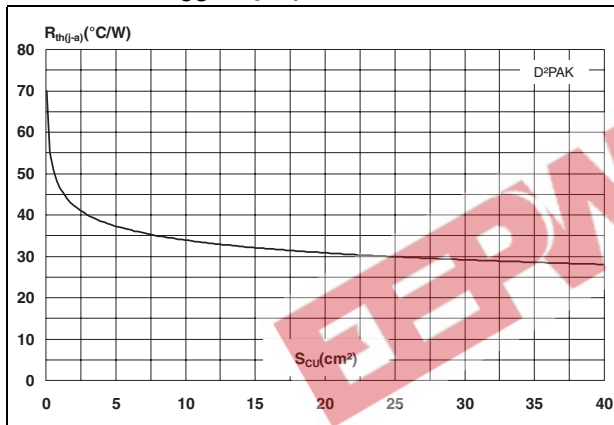
**Figure 9. Relative variation of critical rate of decrease of main current (di/dt)<sub>c</sub> versus junction temperature**



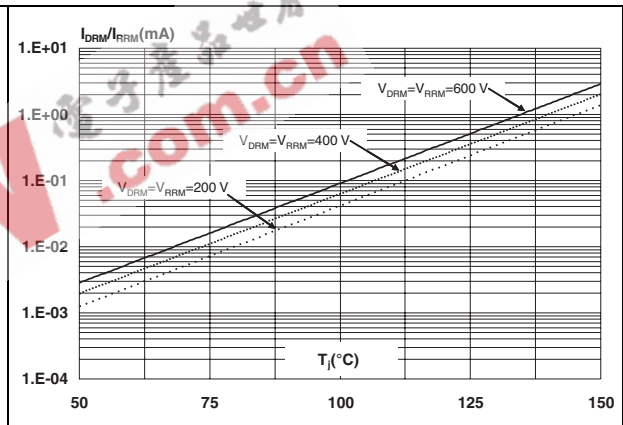
**Figure 10. Relative variation of critical rate of decrease of main current (di/dt)<sub>c</sub> vs reapplied dV/dt (typical values)**



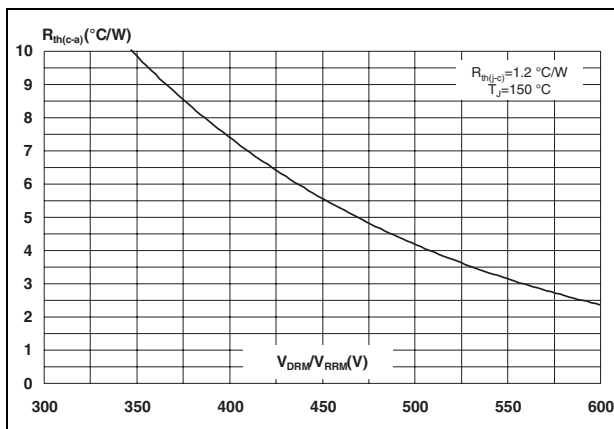
**Figure 11. Variation of thermal resistance, junction to ambient versus copper surface under tab (PCB FR4, e<sub>CU</sub> 35 μm)**



**Figure 12. Leakage current versus junction temperature for different values of blocking voltage (typical values)**



**Figure 13. Acceptable repetitive peak off-state voltage versus case-ambient thermal resistance**



## 2 Ordering information scheme

	T	16	35	H	-	600	I	(-TR)
<b>Triac series</b>								
<b>Current</b> 16 = 16 A								
<b>Sensitivity</b> 35 = 35 mA								
<b>High temperature</b>								
<b>Voltage</b> 600 = 600 V								
<b>Package</b> G = D <sup>2</sup> PAK I = TO-220AB Ins T = TO-220AB								
<b>Packing mode</b> Blank = Tube (D <sup>2</sup> PAK) -TR = Tape and reel (D <sup>2</sup> PAK) RG = Tube (TO-220AB)								

### 3 Package information

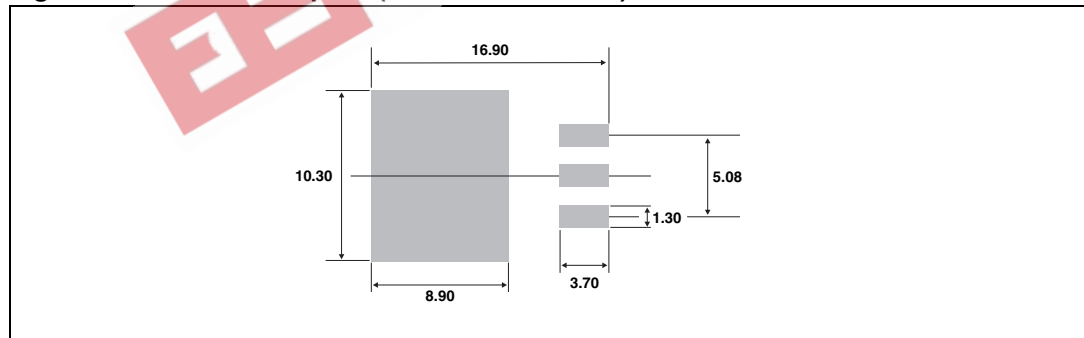
Table 5. TO-220AB and TO-220AB Insulated dimensions

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
Ø1	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	

Table 6. D<sup>2</sup>PAK Mechanical data

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.49	2.69	0.098	0.106
A2	0.03	0.23	0.001	0.009
B	0.70	0.93	0.027	0.037
B2	1.14	1.70	0.045	0.067
C	0.45	0.60	0.017	0.024
C2	1.23	1.36	0.048	0.054
D	8.95	9.35	0.352	0.368
E	10.00	10.40	0.393	0.409
G	4.88	5.28	0.192	0.208
L	15.00	15.85	0.590	0.624
L2	1.27	1.40	0.050	0.055
L3	1.40	1.75	0.055	0.069
M	2.40	3.20	0.094	0.126
R	0.40 typ.		0.016 typ.	
V2	0°	8°	0°	8°

Figure 14. D<sup>2</sup>PAK Footprint (dimensions in mm)



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com).



## 4 Ordering information

Part number	Marking	Package	Weight	Base Qty	Packing mode
T1635H-600G	T1635H-600G	D <sup>2</sup> PAK	1.5 g	50	Tube
T1635H-600G-TR	T1635H-600G	D <sup>2</sup> PAK	1.5 g	1000	Tape and Reel
T1635H-600TRG	T1635H-600T	TO-220AB	2.3 g	50	Tube
T1635H-600IRG	T1635H-600I	TO-220AB Ins	2.3 g	50	Tube

## 5 Revision history

Date	Revision	Changes
31-Aug-2006	1	Initial release

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